# NSN 5961-00-054-7586

Transistor - Page 1 of 1



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**Inclosure Material:** 

Metal

**Overall Length:** 

0.410 inches

**Overall Diameter:** 

0.800 inches

**Mounting Facility Quantity:** 

2

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Germanium

#### Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 75.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 100.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter and 50.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

90.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnp

### Terminal Type And Quantity:

3 pin

## Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

No

## Fiig:

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